NSN 5961-01-226-7916

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-226-7916 **Inclosure Material:** Ceramic **Overall Length:** Between 0.790 inches and 0.810 inches **Overall Height:** Between 0.229 inches and 0.281 inches Overall Width: Between 0.790 inches and 0.810 inches **End Application:** An/arc-190 **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 drain to gate voltage and 80.0 drain to source voltage and 40.0 gate to source voltage **Current Rating Per Characteristic:** 2.00 amperes drain current **Power Rating Per Characteristic:** 40.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 13499-659-1020 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 ribbon and 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: